

STTH102-Y

Automotive high efficiency ultrafast diode

Features

- Very low conduction losses
- Negligible switching losses
- Low forward and reverse recovery times
- High junction temperature
- ECOPACK®2 compliant component
- AEC-Q101 qualified

Description

The STTH102-Y, which is using ST's new 200 V planar technology, is specially suited for switching mode base drive and transistor circuits. The device is also intended for use as a free wheeling diode in power supplies and other power switching applications for automotive.

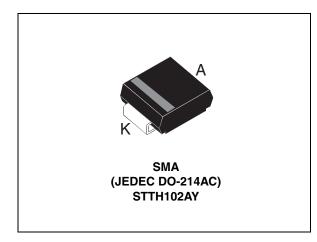


Table 1. Device summary

Symbol	Value
I _{F(AV)}	1 A
V _{RRM}	200 V
T _j (max)	175 °C
V _F (max)	0.78 V
t _{rr} (max)	20 ns

Characteristics STTH102-Y

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Table 2. Absolute rating (limiting values)

Symbol	Parameter	Value	Unit	
V_{RRM}	Repetitive peak reverse voltage			V
I _{F(AV)}	Average forward current	$T_L = 148 ^{\circ}\text{C} \delta = 0.5$	1	Α
I _{FSM}	Surge non repetitive forward current	40	Α	
T _{stg}	Storage temperature range		-65 to + 175	°C
Tj	Operating junction temperature range			°C
dV/dt	Critical rate of rise of reverse voltage			V/µs

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-l)}	Junction to lead	30	°C/W

Table 4. Static Electrical Characteristics

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I _B ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V _R = V _{RRM}			1	μA
'R	$T_j = 125 ^{\circ}\text{C}$	VR - VRRM		1	25	μΛ	
			I _F = 700 mA			0.90	
V _F ⁽²⁾	V _F ⁽²⁾ Forward voltage drop	T _j = 25 °C	I _F = 1 A			0.97	V
			I _F = 1 A		0.68	0.78	

^{1.} Pulse test: $t_p = 5$ ms, $\delta < 2\%$

To evaluate the conduction losses use the following equation: $P = 0.65 \times I_{F(AV)} + 0.130 I_{F^2(RMS)}$

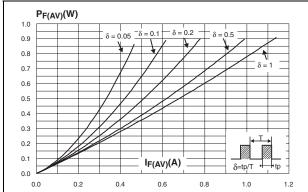
Table 5. Dynamic electrical characteristics

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
t _{rr}	Reverse recovery time	T _j = 25 °C	I _F = 0.5 A I _{rr} = 0.25 A I _R = 1 A		12	20	ns
t _{fr}	Forward recovery time	T _j = 25 °C	$I_F = 1 \text{ A } dI_F/dt = 50 \text{ A/ms}$ $V_{FR} = 1.1 \text{ x } V_F \text{max}$		50		ns
V _{FP}	Forward recovery voltage	T _j = 25 °C	$I_F = 1 A dI_F/dt = 50 A/ms$		1.8		V

^{2.} Pulse test: t_p = 380 μ s, δ < 2%

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Figure 1. Average forward power dissipation Figure 2. Average forward current versus awbient temperature (δ = 0.5)



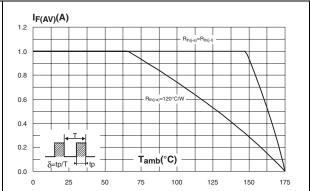
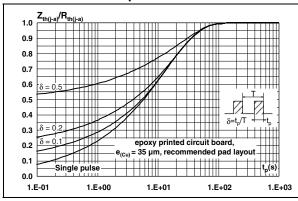


Figure 3. Relative variation of thermal impedance junction to ambient versus pulse duration

Figure 4. Forward voltage drop versus forward current



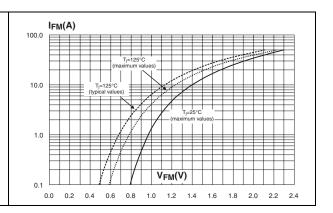
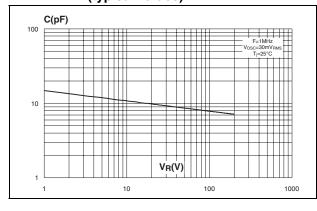
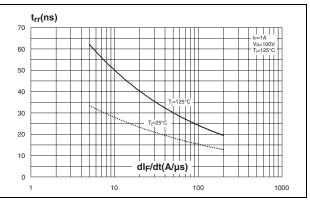


Figure 5. Junction capacitance versus reverse voltage applied (typical values)

Figure 6. Reverse recovery time versus dI_F/dt (90% confidence)





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Figure 7. Peak recovery current versus dl_F/dt Figure 8. Reverse recovery charges versus dl_F/dt (90% confidence)

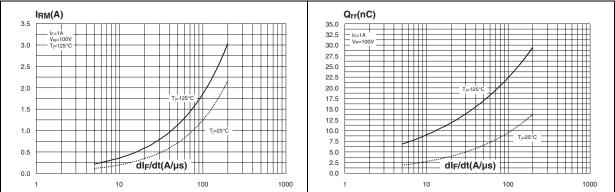
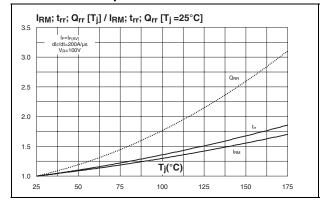
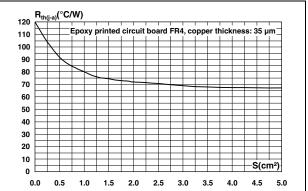


Figure 9. Relative variations of dynamic parameters versus junction temperature

Figure 10. Thermal resistance junction to ambient versus copper surface under each lead





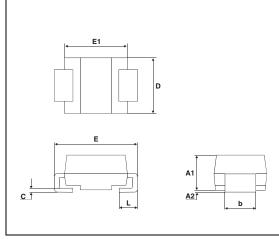
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2 Package information

- Epoxy meets UL94 V0
- Lead-free packages

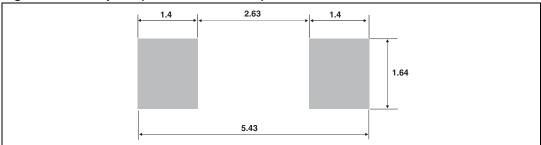
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Table 6. SMA dimensions



	Dimensions					
Ref.	Millin	neters	s Inches			
	Min.	Max.	Min.	Max.		
A1	1.90	2.45	0.075	0.094		
A2	0.05	0.20	0.002	0.008		
b	1.25	1.65	0.049	0.065		
С	0.15	0.40	0.006	0.016		
D	2.25	2.90	0.089	0.114		
Е	4.80	5.35	0.189	0.211		
E1	3.95	4.60	0.156	0.181		
L	0.75	1.50	0.030	0.059		

Figure 11. Footprint (dimensions in mm)



Ordering information STTH102-Y

3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH102AY	U12Y	SMA	0.068 g	5000	Tape and reel

4 Revision history

Table 8. Revision history

Date	Revision	Changes
07-Nov-2011	1	Initial release.

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